

# MMBZ5221ELT1 Series

## Zener Voltage Regulators

### 225 mW SOT-23 Surface Mount

This series of Zener diodes is offered in the convenient, surface mount plastic SOT-23 package. These devices are designed to provide voltage regulation with minimum space requirement. They are well suited for applications such as cellular phones, hand held portables, and high density PC boards.

#### Specification Features:

- 225 mW Rating on FR-4 or FR-5 Board
- Zener Voltage Range – 2.4 V to 91 V
- Package Designed for Optimal Automated Board Assembly
- Small Package Size for High Density Applications
- ESD Rating of Class 3 (>16 kV) per Human Body Model
- Peak Power – 225 W (8 x 20  $\mu$ s)
- Pb-Free Packages are Available

#### Mechanical Characteristics:

**CASE:** Void-free, transfer-molded, thermosetting plastic case

**FINISH:** Corrosion resistant finish, easily solderable

#### MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

**POLARITY:** Cathode indicated by polarity band

**FLAMMABILITY RATING:** UL 94 V-0

#### MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Peak Power Dissipation @ 20 $\mu$ s (Note 1) @ $T_L \leq 25^\circ\text{C}$	$P_{pk}$	225	W
Total Power Dissipation on FR-5 Board, (Note 2) @ $T_A = 25^\circ\text{C}$ Derated above 25°C	$P_D$	225 1.8	mW mW/°C
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Power Dissipation on Alumina Substrate, (Note 3) @ $T_A = 25^\circ\text{C}$ Derated above 25°C	$P_D$	300 2.4	mW mW/°C
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature Range	$T_J, T_{stg}$	-65 to +150	°C

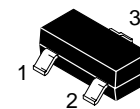
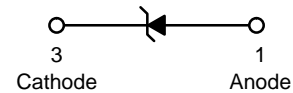
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Nonrepetitive current pulse per Figure 9.
2. FR-5 = 1.0 X 0.75 X 0.62 in.
3. Alumina = 0.4 X 0.3 X 0.024 in., 99.5% alumina.



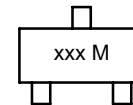
ON Semiconductor®

<http://onsemi.com>



SOT-23  
CASE 318  
STYLE 8

#### MARKING DIAGRAM



xxx = Specific Device Code  
M = Date Code

#### ORDERING INFORMATION

Device	Package	Shipping†
MMBZ52xxELT1	SOT-23	3000/Tape & Reel
MMBZ52xxELT3*	SOT-23	10,000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*MMBZ5246EL, and MMBZ5252EL  
Not Available in 10,000/Tape & Reel.

#### DEVICE MARKING INFORMATION

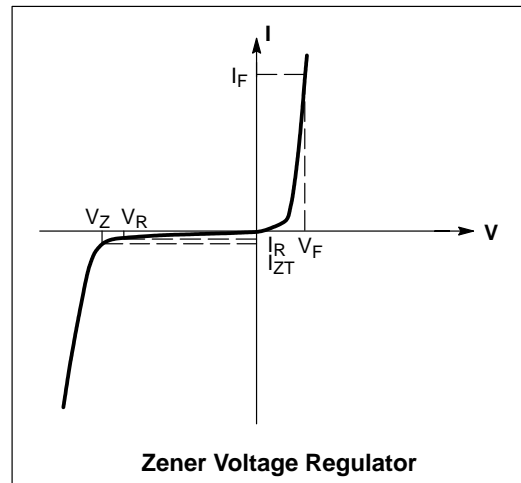
See specific marking information in the device marking column of the Electrical Characteristics table on page 2 of this data sheet.

## MMBZ5221ELT1 Series

### ELECTRICAL CHARACTERISTICS

(Pinout: 1-Anode, 2-No Connection, 3-Cathode) ( $T_A = 25^\circ\text{C}$  unless otherwise noted,  $V_F = 0.95\text{ V Max. @ } I_F = 10\text{ mA}$ )

Symbol	Parameter
$V_Z$	Reverse Zener Voltage @ $I_{ZT}$
$I_{ZT}$	Reverse Current
$Z_{ZT}$	Maximum Zener Impedance @ $I_{ZT}$
$I_{ZK}$	Reverse Current
$Z_{ZK}$	Maximum Zener Impedance @ $I_{ZK}$
$I_R$	Reverse Leakage Current @ $V_R$
$V_R$	Reverse Voltage
$I_F$	Forward Current
$V_F$	Forward Voltage @ $I_F$



### ELECTRICAL CHARACTERISTICS (Pinout: 1-Anode, 2-NC, 3-Cathode) ( $V_F = 0.9\text{ V Max @ } I_F = 10\text{ mA}$ for all types.)

Device	Device Marking	Zener Voltage (Note 4)				Zener Impedance			Leakage Current	
		$V_Z$ (V)			@ $I_{ZT}$	$Z_{ZT}$ @ $I_{ZT}$	$Z_{ZK}$ @ $I_{ZK}$	$I_R$ @ $V_R$		
		Min	Nom	Max	mA	$\Omega$	$\Omega$	mA	$\mu\text{A}$	V
MMBZ5221ELT1G,T3G†	BE2	2.28	2.4	2.52	20	30	1200	0.25	100	1
MMBZ5226ELT1,T3	BE7	3.13	3.3	3.47	20	28	1600	0.25	25	1
MMBZ5228ELT1,T3	BE9	3.70	3.9	4.10	20	23	1900	0.25	10	1
MMBZ5229ELT1,T3	BF1	4.08	4.3	4.52	20	22	2000	0.25	5	1
MMBZ5230ELT1,T3	BF2	4.46	4.7	4.94	20	19	1900	0.25	5	2
<b>MMBZ5231ELT1,T3</b>	<b>BF3</b>	<b>4.84</b>	<b>5.1</b>	<b>5.36</b>	<b>20</b>	<b>17</b>	<b>1600</b>	<b>0.25</b>	<b>5</b>	<b>2</b>
<b>MMBZ5232ELT1,T3</b>	<b>BF4</b>	<b>5.32</b>	<b>5.6</b>	<b>5.88</b>	<b>20</b>	<b>11</b>	<b>1600</b>	<b>0.25</b>	<b>5</b>	<b>3</b>
<b>MMBZ5234ELT1,T3</b>	<b>BF6</b>	<b>5.89</b>	<b>6.2</b>	<b>6.51</b>	<b>20</b>	<b>7</b>	<b>1000</b>	<b>0.25</b>	<b>5</b>	<b>4</b>
<b>MMBZ5235ELT1,T3</b>	<b>BF7</b>	<b>6.46</b>	<b>6.8</b>	<b>7.14</b>	<b>20</b>	<b>5</b>	<b>750</b>	<b>0.25</b>	<b>3</b>	<b>5</b>
MMBZ5236ELT1,T3	BF8	7.12	7.5	7.88	20	6	500	0.25	3	6
MMBZ5237ELT1,T3	BF9	7.79	8.2	8.61	20	8	500	0.25	3	6.5
MMBZ5239ELT1,T3	BG2	8.65	9.1	9.55	20	10	600	0.25	3	7
<b>MMBZ5240ELT1,T3</b>	<b>BG3</b>	<b>9.50</b>	<b>10</b>	<b>10.50</b>	<b>20</b>	<b>17</b>	<b>600</b>	<b>0.25</b>	<b>3</b>	<b>8</b>
<b>MMBZ5242ELT1,T3</b>	<b>BG5</b>	<b>11.40</b>	<b>12</b>	<b>12.60</b>	<b>20</b>	<b>30</b>	<b>600</b>	<b>0.25</b>	<b>1</b>	<b>9.1</b>
MMBZ5243ELT1,T3	BG6	12.35	13	13.65	9.5	13	600	0.25	0.5	9.9
MMBZ5244ELT1,T3	BG7	13.30	14	14.70	9	15	600	0.25	0.1	10
<b>MMBZ5245ELT1,T3</b>	<b>BG8</b>	<b>14.25</b>	<b>15</b>	<b>15.75</b>	<b>8.5</b>	<b>16</b>	<b>600</b>	<b>0.25</b>	<b>0.1</b>	<b>11</b>
MMBZ5246ELT1*	BG9	15.20	16	16.80	7.8	17	600	0.25	0.1	12
<b>MMBZ5248ELT1,T3</b>	<b>BH2</b>	<b>17.10</b>	<b>18</b>	<b>18.90</b>	<b>7</b>	<b>21</b>	<b>600</b>	<b>0.25</b>	<b>0.1</b>	<b>14</b>
<b>MMBZ5250ELT1,T3</b>	<b>BH4</b>	<b>19.00</b>	<b>20</b>	<b>21.00</b>	<b>6.2</b>	<b>25</b>	<b>600</b>	<b>0.25</b>	<b>0.1</b>	<b>15</b>

Devices listed in **bold, italic** are ON Semiconductor **Preferred** devices. **Preferred** devices are recommended choices for future use and best overall value.

4. Zener voltage is measured with a pulse test current  $I_Z$  at an ambient temperature of  $25^\circ\text{C}$ .

†The "G" suffix indicates Pb-Free package available.

\*Not Available in the 10,000/Tape & Reel.

## MMBZ5221ELT1 Series

**ELECTRICAL CHARACTERISTICS (continued)** (Pinout: 1-Anode, 2-NC, 3-Cathode) ( $V_F = 0.9\text{ V Max @ } I_F = 10\text{ mA}$  for all types.)

Device	Device Marking	Zener Voltage (Note 5)				Zener Impedance			Leakage Current	
		$V_Z$ (V)			@ $I_{ZT}$	$Z_{ZT}$ @ $I_{ZT}$	$Z_{ZK}$ @ $I_{ZK}$		$I_R$ @ $V_R$	
		Min	Nom	Max	mA	$\Omega$	$\Omega$	mA	$\mu\text{A}$	V
MMBZ5252ELT1*	BH6	22.80	24	25.20	5.2	33	600	0.25	0.1	18
MMBZ5253ELT1,T3	BH7	23.75	25	26.25	5	35	600	0.25	0.1	19
<b>MMBZ5254ELT1,T3</b>	<b>BH8</b>	<b>25.65</b>	<b>27</b>	<b>28.35</b>	<b>4.6</b>	<b>41</b>	<b>600</b>	<b>0.25</b>	<b>0.1</b>	<b>21</b>
MMBZ5255ELT1,T3	BH9	26.60	28	29.40	4.5	44	600	0.25	0.1	21
MMBZ5256ELT1,T3	BJ1	28.50	30	31.50	4.2	49	600	0.25	0.1	23
<b>MMBZ5257ELT1,T3</b>	<b>BJ2</b>	<b>31.35</b>	<b>33</b>	<b>34.65</b>	<b>3.8</b>	<b>58</b>	<b>700</b>	<b>0.25</b>	<b>0.1</b>	<b>25</b>
MMBZ5258ELT1,T3	BJ3	34.20	36	37.80	3.4	70	700	0.25	0.1	27
MMBZ5262ELT1,T3	BJ7	48.45	51	53.55	2.5	125	1100	0.25	0.1	37
MMBZ5263ELT1,T3	BJ8	53.20	56	58.80	2.2	150	1300	0.25	0.1	43
MMBZ5265ELT1	BK1	58.90	62	65.10	2	185	1400	0.25	0.1	47

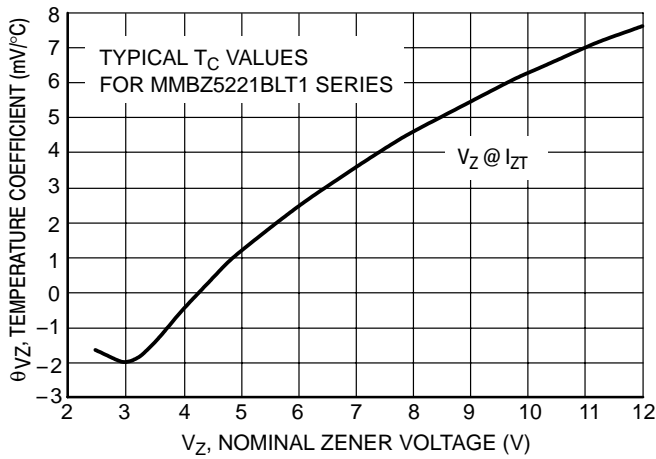
Devices listed in **bold, italic** are ON Semiconductor **Preferred** devices. **Preferred** devices are recommended choices for future use and best overall value.

5. Zener voltage is measured with a pulse test current  $I_Z$  at an ambient temperature of 25°C.

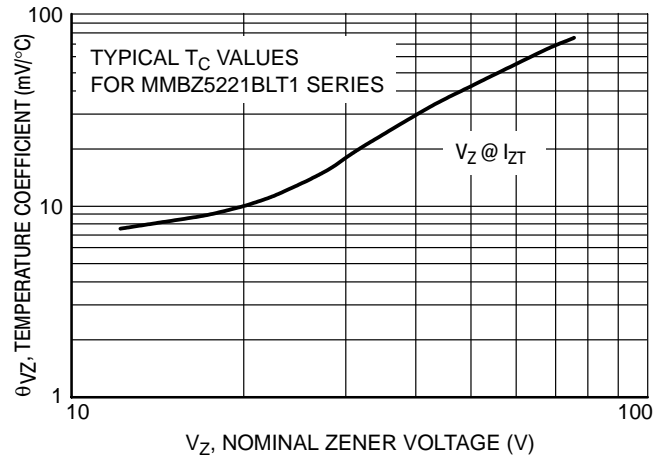
\*Not Available in the 10,0000/Tape & Reel.

# MMBZ5221ELT1 Series

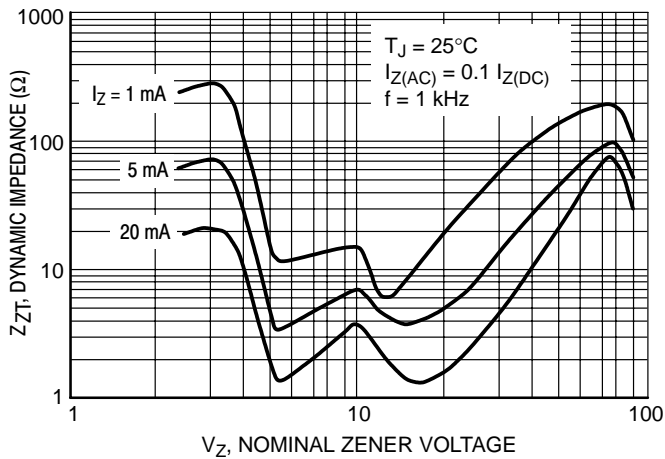
## TYPICAL CHARACTERISTICS



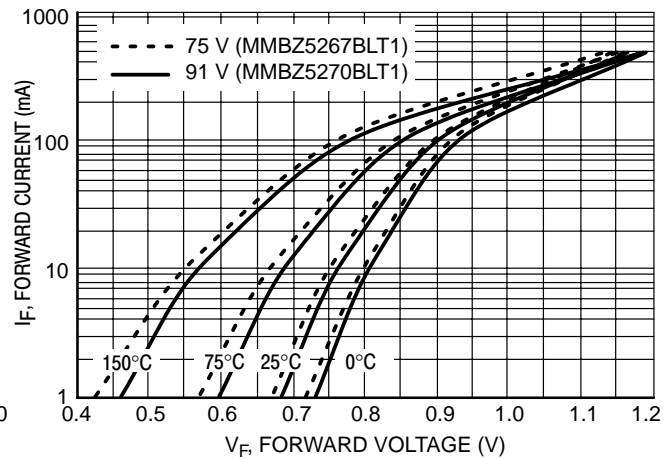
**Figure 1. Temperature Coefficients  
(Temperature Range -55°C to +150°C)**



**Figure 2. Temperature Coefficients  
(Temperature Range -55°C to +150°C)**



**Figure 3. Effect of Zener Voltage on  
Zener Impedance**



**Figure 4. Typical Forward Voltage**

# MMBZ5221ELT1 Series

## TYPICAL CHARACTERISTICS

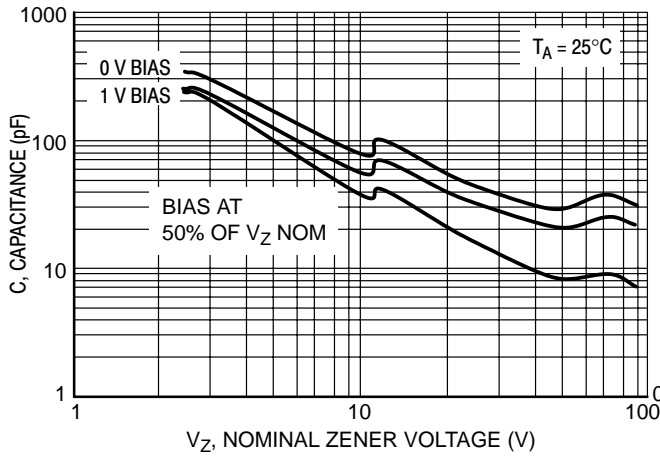


Figure 5. Typical Capacitance

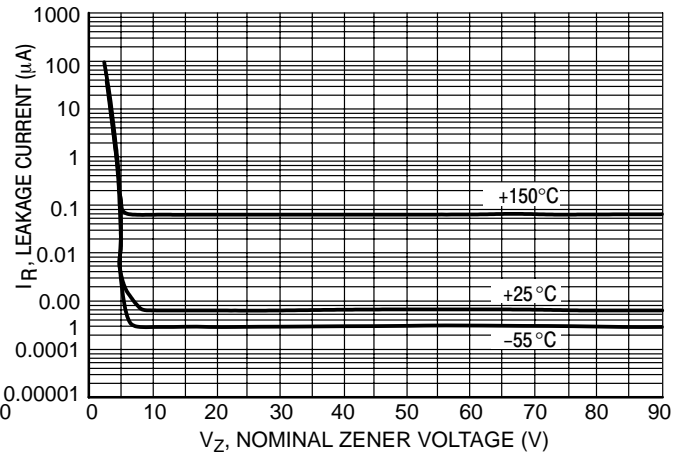


Figure 6. Typical Leakage Current

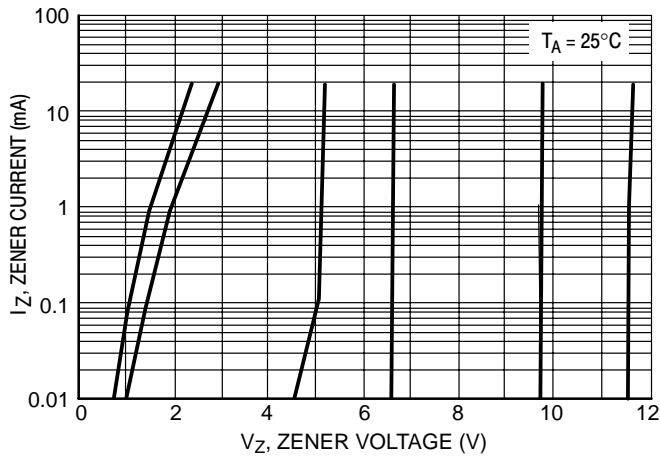


Figure 7. Zener Voltage versus Zener Current ( $V_Z$  Up to 12 V)

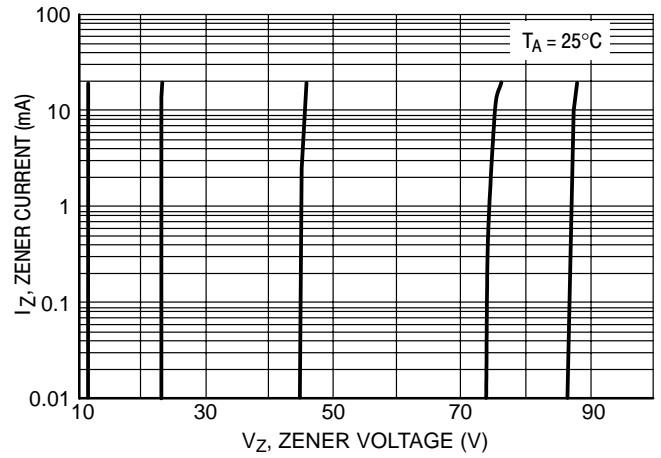


Figure 8. Zener Voltage versus Zener Current (12 V to 91 V)

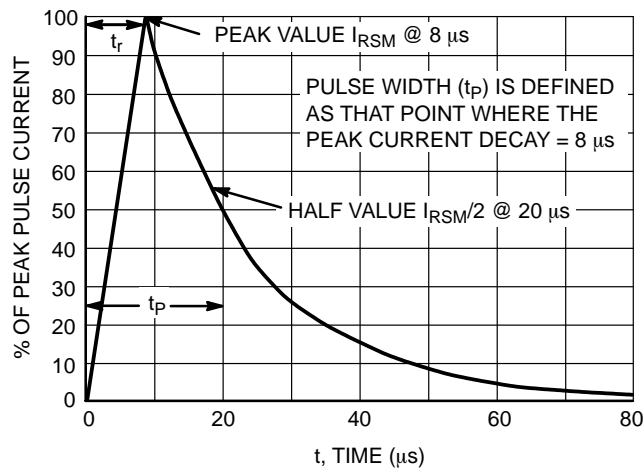
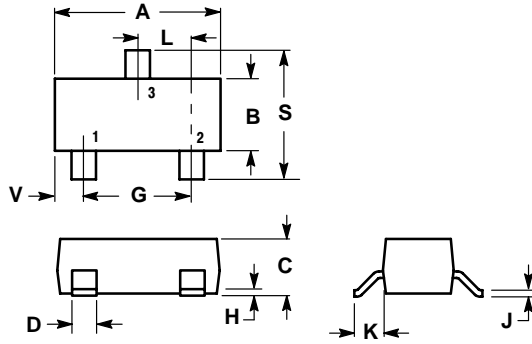


Figure 9.  $8 \times 20 \mu\text{s}$  Pulse Waveform

# MMBZ5221ELT1 Series

## PACKAGE DIMENSIONS

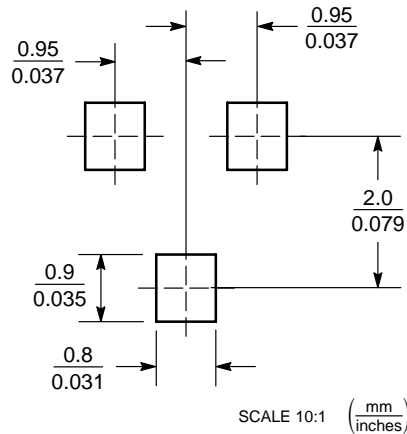
SOT-23  
TO-236AB  
CASE 318-08  
ISSUE AK




- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
  4. 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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